PCN Num	be	r:	<mark>20</mark>	<mark>13(</mark>	<mark>)903003B</mark>				PCN Da	<b>te:</b> 1	0/15/2014	
Title:	_	ualification c evices	of A	SES	SH, TITL and JC	CAP as Add	litional A	sse	mbly / Tes	t Site fo	or Select	
Customer Contact: PCN_ww_admi			min	_te	am@list.ti.com	Phone:	+1(214	1)48	0-6037	Dept:	ept: Quality Services	
Change Ty	/p	e:										
Assembly Site					Assembly Pro			$\square$	Assembly			
Desig	-				Electrical Spe				Mechanic		fication	
Test					Packing/Shipp		ing		Test Proc			
		Bump Site			Wafer Bump I			<u> </u>	Wafer Bu			
Wate	r٢	ab Site			Wafer Fab Ma				Wafer Fal	b Proces	SS	
					Part number o	change I Details						
Decerimtic		of Changes			PCN	Details	>					
		of Change:		- <b>-</b> -	levices in the P				. (ith stu		·	
		iis change.										
Devices wit	:h	<mark>strikethroug</mark>	h a	nd	not highlighted	l in yellow	has bee	n re	etracted un	der rev	A.	
Group 1 D	ev	vice: HNT to	o As	SES	SH							
					н	Т			AS	ESH		
Wire type					1.0 M	1il Au			1.0	Mil Cu		
Mold Com	ро	und	450179						EN20	00515		
Group 2 D	ev	vice: AMKO	R K	(1 t	o TITL							
					АМКС	DR K1			T	(TL		
Lead finis	า				Matt	e Sn			NiF	<b>'</b> dAu		
Mold Com	ро	und			10131	19570				5442		
Group 3 D	e١	vice: STS to	JC	ΆΡ	1							
					STS					P-AT		
Bump Sit	e				STS	-BP			JCA	P-FAB		
Test covera test MQ.	ge	e, insertions,	, со	ndi	tions will remai	in consiste	ent with	curr	ent testing	and ve	rified with	
Reason fo	r (	Change:										
Continuity	of	Supply										
Anticipate	d	Impact on	Fit,	, Fo	orm, Function	, Quality	or Relia	bili	ity (Positi	ve / Ne	egative):	

## **Changes to Product Identification Resulting from this PCN: Group 1 Device: HNT to ASESH**

Assembly Site								
Hana Thailand	Assembly Site Origin (22L)	ASO: HNT						
ASE Shanghai	Assembly Site Origin (22L)	ASO: ASH						
ASSEMBLY SITE CODES: HNT =H, ASESH = A								

## **Group 2 Device: AMKOR K1 to TITL**

Assembly Site						
AMKOR Korea K1	Assembly Site Origin (22L)	ASO: AMN				
TI Taiwan	Assembly Site Origin (22L)	ASO: TAI				
ASSEMBLY SITE CODES: AMN =7, TITL = T						

## **Group 3 Device: SCS to JCAP**

Assembly Site		
STATS ChipPAC-AT	Assembly Site Origin (22L)	ASO: STS
JCAP-AT	Assembly Site Origin (22L)	ASO: JCP
ACCEMPLY CITE CODEC. CTC		

(D) 0336

ASSEMBLY SITE CODES: STS =G, JCAP = P

Sample product shipping label (not actual product label)



Product Affected: Group 1 Device								
OPA1632DGN	THS3202DGNG4	THS4121IDGN	THS4150CDGNG4					
OPA1632DGNG4	THS3202DGNR	THS4121IDGNG4	THS4150CDGNR					
OPA1632DGNR	THS3202DGNRG4	THS4121IDGNR	THS4150CDGNRG4					
OPA1632DGNRG4	THS4011CDGN	THS4121IDGNRG4	THS4150IDGN					
THS3001CDGN	THS4011CDGNG4	THS4130CDGK	THS4150IDGNG4					
THS3001CDGNG4	THS4011CDGNR	THS4130CDGKG4	THS4150IDGNR					
THS3001CDGNR	THS4011CDGNRG4	THS4130CDGN	THS4150IDGNRG4					
THS3001CDGNRG4	THS4011IDGN	THS4130CDGNG4	THS4151CDGK					
THS3001HVCDGN	THS4011IDGNG4	THS4130CDGNR	THS4151CDGKG4					
THS3001HVCDGNG4	THS4011IDGNR	THS4130CDGNRG4	THS4211DGK					
THS3001HVIDGN	THS4011IDGNRG4	THS4130IDGK	THS4211DGKG4					
THS3001HVIDGNG4	THS4022IDGN	THS4130IDGKG4	THS4211DGN					
THS3001IDGN	THS4022IDGNG4	THS4130IDGKR	THS4211DGNG4					
THS3001IDGNG4	THS4022IDGNR	THS4130IDGKRG4	THS4211DGNR					
THS3001IDGNR	THS4022IDGNRG4	THS4130IDGN	THS4211DGNRG4					
THS3001IDGNRG4	THS4031CDGN	THS4130IDGNG4	THS4222DGK					
THS3062DGN	THS4031CDGNG4	THS4130IDGNR	THS4222DGKG4					
THS3062DGNG4	THS4031CDGNR	THS4130IDGNRG4	THS4222DGN					
THS3110IDGN	THS4031CDGNRG4	THS4131CDGK	THS4222DGNG4					
THS3110IDGNG4	THS4031IDGN	THS4131CDGKG4	THS4222DGNR					
THS3110IDGNR	THS4031IDGNG4	THS4131CDGKR	THS4222DGNRG4					

	TUCA	00470 ON 0		THOM			TU 0 4 5		
THS3110IDGNRG4 THS4031IDG								00IDGK	
THS3111CDGNR THS4031IDG			RG4		131CDGN			00IDGKG4	
THS3111CDGNRG4 THS4032CD0					THS4131CDGNG4			00IDGN	
	THS3111IDGN THS4032CDG				131CDGNR			00IDGNG4	
THS3111IDGNG4		032IDGN			131CDGNRG4			00IDGNR	
THS3111IDGNR	THS4	032IDGNC	54	THS4	131IDGK			00IDGNRG4	
THS3111IDGNRG4		032IDGNF			<mark>131IDGKG</mark> 4			<mark>04DGK</mark>	
THS3120CDGN	THS4	032IDGNF	RG4		131IDGKR		THS45	<mark>04DGKG4</mark>	
THS3120CDGNG4	THS4	121CDGK		THS4	<mark>131IDGKRG4</mark>		THS45	04DGN	
THS3120CDGNR	THS4	121CDGK	<mark>64</mark>	THS4	131IDGN		THS45	04DGNG4	
THS3120CDGNRG4	THS4	121CDGKI	R	THS4	131IDGNG4		THS45	04DGNR	
THS3120IDGN	THS4	121CDGKI	RG4	THS4	131IDGNR		THS45	04DGNRG4	
THS3120IDGNG4	THS4	121CDGN		THS4	131IDGNRG4		THS45	<mark>05DGK</mark>	
THS3121IDGN	THS4	121CDGN	G4	THS4	140CDGN		THS45	<mark>05DGKG4</mark>	
THS3121IDGNG4	THS4	121CDGN	R	THS4	140CDGNG4		THS45	05DGN	
THS3202DGK	THS4	121CDGN	RG4	THS4	140IDGN		THS45	05DGNG4	
THS3202DGKG4	THS4	121IDGK		THS4	140IDGNG4		THS45	05DGNR	
THS3202DGKR	THS4	121IDGKC	<mark>64</mark>	THS4	140IDGNR		THS45	05DGNRG4	
THS3202DGKRG4	THS3202DGKRG4 THS4121I		<mark>t</mark>	THS4	140IDGNRG4		THS60	72IDGNR	
THS3202DGN	121IDGKR	<mark>G4</mark>	THS4	150CDGN		THS60	72IDGNRG4		
Product Affected: Gr	oup 2	Device							
MSP430V250IPZ									
Product Affected: Gr	oun 3	Device							
CDC3RL02YFPR		22932BYF	PR	TPS	22932BYFPT				
CDCSREUZITIR		22992011	11	1110	229520111				
		Oualifi	catio	Dat	a Group 1				
This qualification has been	n specifi				a: Group 1			qualification data	
validates that the propose									
	_					-			
	Qua				GK (MSL1-2	60C)	)		
A e e e re h lu	· Cite ·		ge Con	struct	ion Details				
Assembly		ASESH			Mold C			EN2000515	
# Pins-Designator, F		8-DGK, N			Mount C			EY1000063	
Lead Finish		/			E	Bond	Wire:	1.0 Mil Dia. Cu	
	lan	🛛 Test R					1		
Reliability Test		C	onditior	ons			Sample Size / Fail		
Electrical Characterizat	ion	-   -					Pass		
**Temperature Cycle			-65C/+150C (500 Cyc)			77/0			
						Pass			
Moisture Sensitivity L1-260C 12/0									
Notes **- Preconditioning sequence: Level 1-260C.									

<b>Reference Qualification</b>	n						
Qua			KR (MSL1-260C)	)			
		kage Construct					
Assembly Site:	ASESH	1	Mold Comp	ound:	EN2000	515	
<pre># Pins-Designator, Family:</pre>	8-DGk	K, MSOP	Mount Comp	ound:	EY1000	063	
Lead Finish, Base		•	Bond	Wire:	1.0 Mil	Dia.	Cu
Qualification: 🗌 Plan	🛛 Test	Results					
Reliability Test		Conditions		Sa	ample Si	ze /	Fail
				Lot#	1 Lot#2 Lot#		Lot#3
**Steady-state Life Test		150C (168 Hou		77/0	) 77/	′0	77/0
**High Temp. Storage Bake		150C (500 Hou	rs)	77/0	) 77/	′0	77/0
**Biased HAST		130C/85%RH (	96 Hours)	77/0	) 77/	′0	77/0
**Autoclave 121C		121C, 2 atm (9	6 Hours)	77/0	) 77/	′0	77/0
**Temperature Cycle		-65C/+150C (5	00 Cyc)	77/0	) 77/	′0	77/0
Solderability		Steam age, 8 H	ours	22/0	) 22/	′0	22/0
Flammability		Method A - UL9	4-0	5/0	5/0	0	5/0
Flammability		Method B - IEC	695-2-2	5/0	5/0	0	5/0
Flammability		Method C - UL	5/0	5/0	0	5/0	
Salt Atmosphere		24 Hours	5/0	5/0	0	5/0	
Manufacturability (MQ)	(per mfg. Site s	specification)	Pass	s Pas	s	Pass	
Moisture Sensitivity		L1-260C	12/0	) 12/	′0	12/0	
Notes **- Preconditioning se	equence	e: Level 1-260C.					
		ification Dat					
This qualification has been specifi validates that the proposed change						on da	ata
Qual	Vehicle	e : MSP430F479	94IPZ (MSL1-260	C)			
	Pac	kage Construct	ion Details				
Assembly Site:	TITL		Mold Comp	ound:	420544	2	
# Pins-Designator, Family:	100-P	Z, LQFP	Mount Comp	4042504			
Lead Finish, Base	NiPdA	u, Cu	Bond	0.95 Mil Dia. Au			
Qualification: Plan	🛛 Test	Results					
Reliability Test		Conditions	Sample Size / Fail				
Electrical Characterization		-	Pass				
**Operating Life Test	150C (300 Hou	120/0					
**Temperature Cycle	-65C/+150C (1	77/0					
**High Temp. Storage Bake	170Ć (420 Hou	77/0					
ESD CDM	+/-500V	3/0					
ESD HBM		+/-2KV	3/0				
ESD MM		+/-500V	3/0				
X-ray		Top side only	5/0				
Manufacturability (MQ)		(per mfg. Site s	specification)		Pas	s	
Notes **- Preconditioning se	equence	e: Level 1-260C.					

Qualification Data: Group 3							
This qualification has been specifically developed for the validation of this change. The qualification data validates that the proposed change meets the applicable released technical specifications.							
Qual	/ehicle : CD3239	(MSL1-260C)					
Pa	ckage Construct	ion Details					
Assembly & Bump Site: JCAF	)	Bump Compos	sition:	SnAgCu			
# Pins-Designator, Family: 25-Y	FP, WCSP	Bump Dian	neter:	0.23mm			
Qualification: 🗌 Plan 🛛 Test Results							
Reliability Test	Conditions	Conditions			ple Size / Fail		
			Lot#1	L Lot#2	Lot#3		
**Steady-state Life Test	150C (300 Hou	150C (300 Hours)			116/0		
**High Temp. Storage Bake	150C (1000 Ho	77/0	77/0	77/0			
**Biased HAST	130C/85%RH (	77/0	77/0	77/0			
**Unbiased HAST	130C/85%RH (96 Hours)		77/0	77/0	77/0		
**Temperature Cycle	-55C/+125C (1	-55C/+125C (1000 Cyc)			77/0		
Manufacturability (MQ)	(per mfg. Site s	Pass	Pass	Pass			
Moisture Sensitivity	L1-260C			12/0	12/0		
Notes **- Preconditioning sequen	ce: Level 1-260C.						

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

Location	E-Mail
USA	PCNAmericasContact@list.ti.com
Europe	PCNEuropeContact@list.ti.com
Asia Pacific	PCNAsiaContact@list.ti.com
Japan	PCNJapanContact@list.ti.com